

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Collector Rose Voltage	AC847	M	50	V	
Collector-Base Voltage	AC848	V _{СВО}	30	v	
Collector-Emitter Voltage	AC847	M	45	N/	
	AC848	V _{CEO}	30	v	
Emitter-Base Voltage	AC847	M	6.0	N	
	AC848	V _{EBO}	5.0	v	
Continuous Collector Current	Ι _C	100	mA		
Peak Collector Current		I _{CM}	200	mA	
Peak Emitter Current		I _{EM}	200	mA	

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Power Dissipation	(Note 6)	D	310	mW	
	(Note 7)	P _D	350		
Thermal Desistance, Junction to Ambient	(Note 6)	5	403	°C/W	
Thermal Resistance, Junction to Ambient	(Note 7)	R _{ÐJA}	357	C/VV	
Thermal Resistance, Junction to Leads	(Note 8)	R _{ƏJL}	350	°C/W	
Operating and Storage Temperature Range		T _J ,T _{STG}	-65 to +150	°C	

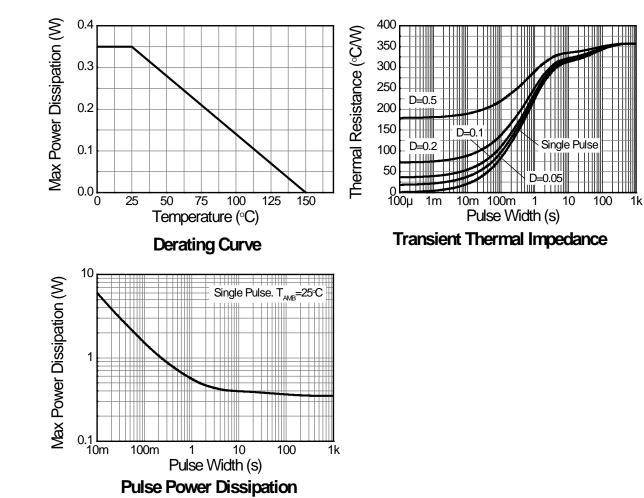
ESD Ratings (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge—Human Body Model	ESD HBM	4000	V	3A
Electrostatic Discharge—Machine Model	ESD MM	400	V	С

6. For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided FR-4 PCB; device is measured under still air Notes: For a device mounted of minimum recommended pad layout 102 copper that is conditions whilst operating in a steady-state.
Same as Note 6 except the device is mounted on 15mm x 15mm 1oz copper.
Thermal resistance from junction to solder-point (at the end of the leads).
Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information





AC847BQ-AC847CQ-AC848BQ

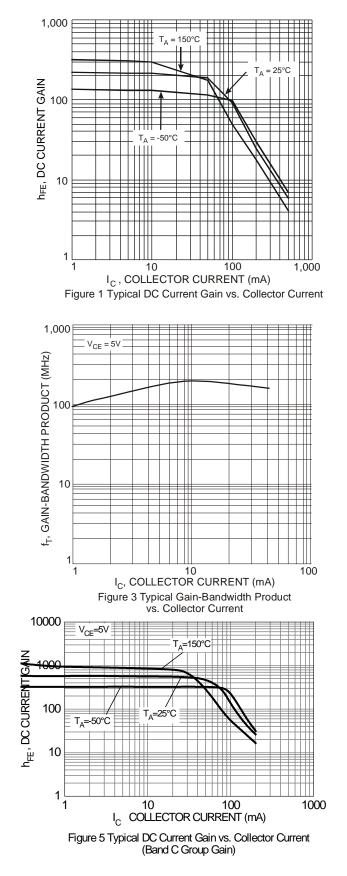
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

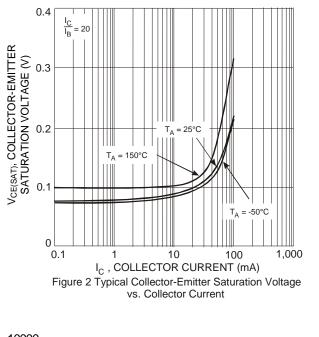
Characteristic			Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage AC847 AC848		ВV _{CBO}	50		_	V	I _C = 10μA	
			30		_	_	<u> </u>	
Collector-Emitter Breakdown Voltage (Note 10) AC847 AC848		BV _{CEO}	45		_	V	$I_{\rm C} = 10 {\rm mA}$	
			30	—	—		—	
Emitter-Base Breakdown Voltage AC847 AC848		BVEBO	6 — V I _E	$I_E = 1 \mu A$				
		DVEBO	5	_	_			
Collector Cutoff Current					15	nA	$V_{CB} = 30V$	
			I _{CBO}	—		5	μA	$V_{CB} = 30V, T_{J} = +150^{\circ}C$
Collector Emitter Cutoff Current			ICES	_	—	15	nA	V _{CE} = 50V
Emitter Base Cutoff Current			I _{EBO}	_		100	nA	V _{EB} = 5V
Small Signal Current Gain (Note 10)	AC847	BQ/AC848BQ	h.		330			
Sinali Signal Current Gain (Note 10)		C847CQ	h _{fe}	_	600	_		
Input Impedance (Note 10)		BQ/AC848BQ	h _{ie}	_	4.5	_	kΩ	
		C847CQ	nie		8.7		K32	$I_{C} = 2.0 \text{mA}, V_{CE} = 5 \text{V}$
Output Admittance (Note 10)		BQ/AC848BQ	h _{oe}		30	_	μs	f=1.0kHz
		C847CQ	100		60			
Reverse Voltage Transfer Ratio (Note 10)		BQ/AC848BQ	h _{re}	—	2x10 ⁻⁴	_	_	
		C847CQ	rre		3x10 ⁻⁴			
DC Current Gain (Note 10)		'BQ/AC848BQ	h _{FE}	200	290	450	—	$I_C = 2.0 \text{mA}, V_{CE} = 5 \text{V}$
	A	C847CQ		420	520	800		
Collector-Emitter Saturation Voltage (Note	10)		$V_{CE(SAT)}$	—	90	250	mV	$I_{\rm C}$ = 10mA, $I_{\rm B}$ = 0.5mA
	10)				200	600		$I_{C} = 100 \text{mA}, I_{B} = 5.0 \text{mA}$
Base-Emitter Turn-On Voltage (Note 10)		V	580	660	700	mV	$I_C = 2mA$, $V_{CE} = 5V$	
			V _{BE(ON)}	_		770	IIIV	$I_{C} = 10 \text{mA}, V_{CE} = 5 \text{V}$
Base-Emitter Saturation Voltage (Note 10)		V _{BE(SAT)}	—	700		mV	$I_{C} = 10 \text{mA}, I_{B} = 0.5 \text{mA}$	
				900	_		$I_{\rm C} = 100 {\rm mA}, I_{\rm B} = 5 {\rm mA}$	
Output Capacitance		C _{OBO}	_	3	_	pF	$V_{CB} = 10V, f = 1.0MHz$	
Transition Frequency		f⊤	100	300	_	MHz	$V_{CE} = 5V, I_C = 10mA,$ f = 100MHz	
Noise Figure		NF		2	10	dB	V _{CE} =5V, I _C =200μA R _S =2kΩ, f=1kHz ∆f=200Hz	

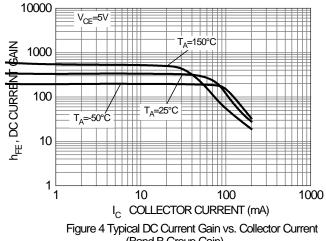
Note: 10. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)





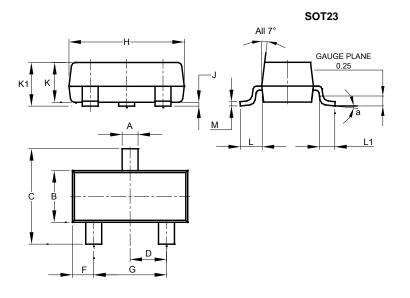


(Band B Group Gain)



Package Outline Dimensions

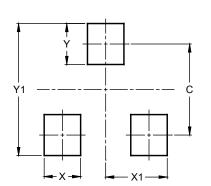
Please see http://www.diodes.com/package-outlines.html for the latest version.



	SOT23					
Dim	Min	Max	Тур			
Α	0.37	0.51	0.40			
В	1.20	1.40	1.30			
С	2.30	2.50	2.40			
D	0.89	1.03	0.915			
F	0.45	0.60	0.535			
G	1.78	2.05	1.83			
н	2.80	3.00	2.90			
J	0.013	0.10	0.05			
ĸ	0.890	1.00	0.975			
K1	0.903	1.10	1.025			
L	0.45	0.61	0.55			
L1	0.25	0.55	0.40			
М	0.085	0.150	0.110			
а	0°	8°				
All	All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23

Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9



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